1. Record Nr. UNINA9910792198503321

Autore	Cohen Robert <1938-, >
Titolo	Acting power : the 21st century edition / / Robert Cohen
Pubbl/distr/stampa	London ; ; New York : , : Routledge, , 2013
ISBN	1-135-12316-0 0-203-07599-4 1-299-27928-7 1-135-12317-9
Descrizione fisica	1 online resource (265 p.)
Disciplina	792.02/8
Soggetti	Acting
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	Description based upon print version of record.
Nota di bibliografia	Includes bibliographical references and index.
Nota di contenuto	Introduction: the actor's viewpoint -- Out of the self -- Into the other -- Playing character -- Playing style -- Playing the performance -- Acting power: a synthesis.
Sommario/riassunto	'Robert Cohen's book, Acting Power, follows the tradition of his other book, Acting One, and has been the veritable bible for acting teachers for the last quarter century.' - David Krasner, Emerson College'This book, above all else, is an attempt to explore the qualities of acting power.... to suggest to you, the actor, an approach toward not merely good acting but powerful acting. Great actors display the power to frighten - and the power to seduce - and can shift between the one and the other like a violinist can her notes.' - From th

2. Record Nr. UNINA9910566483803321

Autore	Sverdlov Viktor
Titolo	Magnetic and Spin Devices
Pubbl/distr/stampa	Basel, : MDPI - Multidisciplinary Digital Publishing Institute, 2022
Descrizione fisica	1 online resource (84 p.)
Soggetti	Physics Research & information: general
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Sommario/riassunto	As the scaling of electronic semiconductor devices displays signs of saturation, the main focus of research in microelectronics is shifting towards finding new computing paradigms. Electron spin offers additional functionality to digital charge-based devices. Several fundamental problems, including spin injection to a semiconductor, spin propagation and relaxation, and spin manipulation by the gate voltage, have been successfully resolved to open a path towards spin-based reprogrammable electron switches. Devices employing electron spin are nonvolatile; they are able to preserve the stored information without external power. Emerging nonvolatile devices are electrically addressable, possess a simple structure, and offer endurance and speed superior to flash memory. Having nonvolatile memory very close to CMOS offers a prospect of data processing in the nonvolatile segment, where the same devices are used to store and process the information. This opens perspectives for conceptually new low-power computing paradigms within Artificial Intelligence of Things (AIoT). This Special Issue focuses on all topics related to spintronic devices such as spin-based switches, magnetoresistive memories, energy harvesting devices, and sensors that can be employed in in-memory computing concepts and in Artificial Intelligence.